## NSN 5961-01-345-4232

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-345-4232 **Inclosure Material:** Glass **Overall Length:** 0.520 inches **Overall Diameter:** 1.610 inches **End Application:** Communication restoral system an/tsc-115 **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 400.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig: A110a0